

# YJ Planar Schottky Barrier Diode Die Specification

150V 2A, 45mil, Schottky barrier diode die based on silicon planar process  
Part No.: PSB045H150SS-280A

## Main Products Characterstics

### Maximum Ratings

### Static Electrical Characteristics (Ta = 25°C)

$I_F = 2\text{ A}$

2%

### Device Schematics and Outline Drawing

Die Thickness \*

Die Size \*\*

Top Metal Pad

Active Area

Top Metal

Bac20.2 530.811.16 rev 3.0 (Bac)D [Bac20.2 530.81sng (x-none)-BD